

#### General Description

Maxim's DG528/DG529 are monolithic, 8-channel, CMOS multiplexers with on-board address and control latches that simplify design and reduce board space in microprocessor-based applications. The DG528 is a single-ended, 1-of-8 multiplexer, while the DG529 is a differential, 2-of-8 multiplexer. These devices can operate as multiplexers or demultiplexers.

The DG528/DG529 have break-before-make switching to prevent momentary shorting of the input signals. Each device operates with dual supplies (±4.5V to ±20V) or a single supply (+5V to +30V). All logic inputs are TTL and CMOS compatible. The Maxim DG528/DG529 are pin and electrically compatible with the industry-standard DG528/DG529.

#### Applications

Data-Acquisition Systems Automatic Test Equipment Avionics and Military Systems Communication Systems Microprocessor-Controlled Systems Audio-Signal Multiplexing

#### Features

- **♦ Low-Power, Monolithic CMOS Design**
- ♦ On-Board Address Latches
- ♦ Break-Before-Make Input Switches
- **♦ TTL and CMOS Logic Compatible**
- **♦ Microprocessor-Bus Compatible**
- ♦ rps(on) < 400Ω
- ♦ Pin and Electrically Compatible with the Industry-Standard DG528/DG529 and ADG528/ADG529

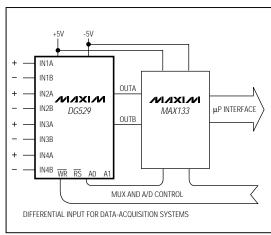
#### Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
DG528CJ	0°C to +70°C	18 Plastic DIP
DG528CWN	0°C to +70°C	18 Wide SO
DG528CK	0°C to +70°C	18 CERDIP
DG528C/D	0°C to +70°C	Dice*
DG528DJ	-40°C to +85°C	18 Plastic DIP
DG528DN	-40°C to +85°C	20 PLCC
DG528EWN	-40°C to +85°C	18 Wide SO
DG528DK	-40°C to +85°C	18 CERDIP
DG528AZ	-55°C to +125°C	20 LCC**
DG528AK	-55°C to +125°C	18 CERDIP**

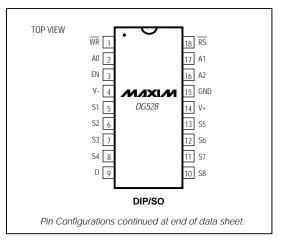
#### Ordering Information continued at end of data sheet.

- Contact factory for dice specifications.
- \*\* Contact factory for availability and processing to MIL-STD-883.

### Typical Operating Circuit



#### Pin Configurations



MIXIM

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#### **ABSOLUTE MAXIMUM RATINGS**

Voltage Referenced to V-	
	+44V
GND	+25V
Digital Inputs Vs, VD	V2V to V+ +2V
1	or 20mA, whichever occurs first.
Current (any terminal, except S	or D)30mA
Continuous Current, S or D	
Peak Current, S or D	20mA
(pulsed at 1ms, 10% duty cyc	cle max)50mA
Continuous Power Dissipation	
	11mW/°C above +70°C)889mW

18-Pin Wide SO (derate 9.52mW/°C above +70°C)762mW 18-Pin CERDIP (derate 10.53mW/°C above +70°C)842mW 20-Pin PLCC (derate 10.00mW/°C above +70°C)800mW
20-Pin LCC (derate 9.09mW/°C above +70°C)727mW
Operating Temperature Ranges
DG52_C0°C to +70°C
DG52_D_/E40°C to +85°C
DG52_A55°C to +125°C
Storage Temperature Range65°C to +150°C

Lead Temperature (soldering, 10sec) .....+300°C

Note 1: All leads are soldered or welded to PC board.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### **ELECTRICAL CHARACTERISTICS**

 $(V = 15V, V = .15V, V_{EN} = 2.4V, \overline{WR} = 0V, \overline{RS} = 2.4V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.})$ 

PARAMETER	SYMBOL	CONDITIONS				DG52_A TYP	MAX	DO MIN	G52_C/D TYP	/E MAX	UNITS
SWITCH											
Analog-Signal Range	VANALOG	(Note 2)			-15		15	-15		15	V
Drain-Source	rDS(ON)	\/D = \ 10\\/ \/A\ = 0 0\\/		$T_A = +25^{\circ}C$ , $T_{MIN}$		270	400		270	450	Ω
On-Resistance	103(014)	(Note 3)		$T_A = T_{MAX}$			500			500	
Greatest Change in Drain- Source On-Resistance Between Channels	Δr <sub>DS</sub> (ON)	-10V < V <sub>S</sub> < 10V		T <sub>A</sub> = +25°C		6			6		%
Source-Off Leakage	1	V <sub>EN</sub> = 0V, V <sub>S</sub> =	±10V,	$T_A = +25^{\circ}C$	-1	-0.005	1	-5	-0.005	5	Λ
Current	Is(off)	$V_D = \pm 10V$	= ±10V		-50	-0.005	50	-50	-0.005	50	nA
	I <sub>D(OFF)</sub>	$V_{EN} = 0V,$ $V_{S} = \pm 10V,$ $V_{D} = \pm 10V$	DG528	T <sub>A</sub> = +25°C	-10	-0.015	10	-20	-0.015	20	- nA
Drain-Off Leakage Current				$T_A = T_{MAX}$	-200	-0.015	200	-200	-0.015	200	
			DG529	$T_A = +25^{\circ}C$	-10	-0.008	10	-20	-0.008	20	
				$T_A = T_{MAX}$	-100	-0.008	100	-100	-0.008	100	
		V <sub>AH</sub> = 2.4V,	DG528 DG529	$T_A = +25^{\circ}C$	-10	-0.03	10	-20	-0.03	20	nA
Drain-On Leakage	Invovo	$V_S = V_D = \pm 10V$ ,		$T_A = T_{MAX}$	-200	-0.03	200	-200	-0.03	200	
Current (Notes 3, 4)	I <sub>D(ON)</sub>	VAL = 0.8V, VEN = 2.4V		$T_A = +25^{\circ}C$	-10	-0.015	10	-20	-0.015	20	
				$T_A = T_{MAX}$	-100	-0.015	100	-100	-0.015	100	
INPUT											
	I <sub>AH</sub>	V <sub>Δ</sub> = 2.4V		$T_A = +25^{\circ}C$	-1	-0.002	1	-1	-0.002	1	
Address Input Current, Input Voltage High		VA = 2.4V		$T_A = T_{MAX}$	-30			-30			μΑ
		V <sub>A</sub> = 15V		$T_A = +25^{\circ}C$	-1	-0.006	1	-1	-0.006	1	]
		vA - 12v		$T_A = T_{MAX}$			30			30	
Address Input Current,	I <sub>AL</sub>		$V_A = \overline{RS} = \overline{WR} = 0V$ ,		-1	-0.002	1	-1	-0.002	1	μA
Input Voltage Low		$V_{EN} = 0V \text{ or } 2.4V$		$T_A = T_{MAX}$	-30	-0.01		-30	-0.01		_ '

#### **ELECTRICAL CHARACTERISTICS**

(V+ = 15V, V- = -15V,  $V_{EN}$  = 2.4V,  $\overline{WR}$  = 0V,  $\overline{RS}$  = 2.4V,  $T_A$  =  $T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS			MIN	DG52_A TYP	MAX	l	G52_C/D	)/E MAX	UNITS
DYNAMIC				IVIIIA	111	WIAA	IVIIIV	111	IVIAA		
Switching Time of Multiplexer	trans	Figure 1		T <sub>A</sub> = +25°C		0.4	1			1.5	μs
Break-Before-Make Interval	topen	Figure 2		T <sub>A</sub> = +25°C		0.2			0.2		μs
Enable, Write Turn-On Time	ton(en, WR)	Figures 3, 4		T <sub>A</sub> = +25°C		1.0	1.5			1.5	μs
Enable, Reset Turn-Off Time	toff(en, RS)	Figures 3, 5		T <sub>A</sub> = +25°C		0.4	1			1.5	μs
Charge Injection	Q	Figure 6		T <sub>A</sub> = +25°C		4			4		рС
Off Isolation	OIRR	$\begin{split} &V_{EN}=0V,R_L=1k\Omega,\\ &C_L=15pF,\\ &V_S=7V_{RMS},f=500kHz \end{split}$		T <sub>A</sub> = +25°C		68			68		dB
Logic-Input Capacitance	CIN	f = 1MHz		T <sub>A</sub> = +25°C		2.5			2.5		pF
Source-Off Capacitance	C <sub>S(OFF)</sub>	V <sub>EN</sub> = 0V, f = 14 V <sub>S</sub> = 0V	0kHz,	T <sub>A</sub> = +25°C		5			5		pF
Drain-Off Capacitance	C <sub>D(OFF)</sub>	V <sub>EN</sub> = 0V, DG528 f = 140kHz.		T <sub>A</sub> = +25°C		25			25		pF
·	=(=,	$V_S = 0V$	DG529	T <sub>A</sub> = +25°C	12			12			
SUPPLY											
Positive Supply Current	+	V <sub>EN</sub> = V <sub>AH</sub> = 0V		T <sub>A</sub> = +25°C		0.003	2.5		0.003	2.5	mA
Negative Supply Current	l-	V <sub>EN</sub> = V <sub>AH</sub> = 0V		T <sub>A</sub> = +25°C	-1.5	0.01		-1.5	0.01		mA
MINIMUM INPUT TIMIN	G										
WR Pulse Width	tww	Figure 7		300	150		300	15		ns	
AX, EN Data Valid to WR	t <sub>DW</sub>	(Stabilization Time) Figu		re 7	180	120		180	12		ns
AX, EN Data Valid after WR	t <sub>WD</sub>	(Hold Time) Fig	ure 7		30	10		30	10		ns
RS Pulse Width	t <sub>RS</sub>	Figure 7; $V_S = 5$	V (Note	5)	500	150		500	150		ns

Note 2: Guaranteed by design.

Note 3: Sequence each switch on.

Note 4: I<sub>D(ON)</sub> is leakage from driver into on switch.

Note 5: Reset pulse period must be at least 50µs during or after power-on.

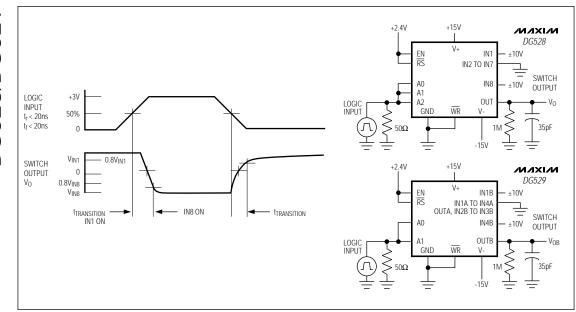


Figure 1. Transition-Time Test Circuits

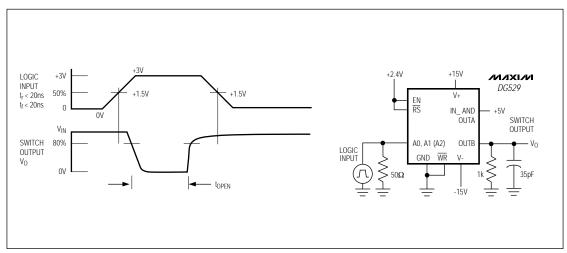


Figure 2. Open-Time (B.B.M.) Interval Test Circuit

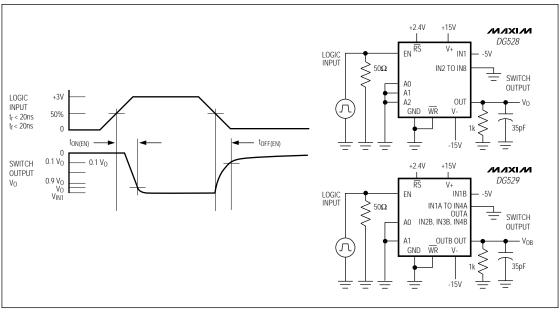


Figure 3. Enable ton/toff Time Test Circuit

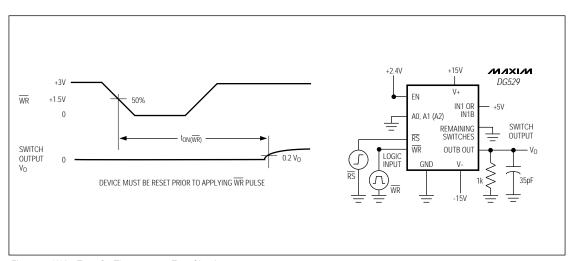


Figure 4. Write Turn-On Time  $t_{ON(\overline{WR})}$  Test Circuit

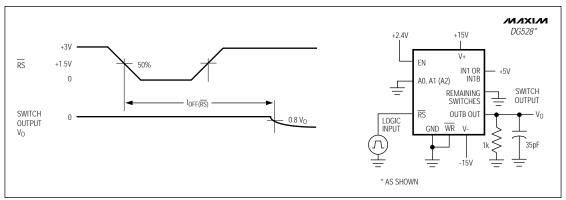


Figure 5. Reset Turn-Off Time  $t_{OFF}(\overline{RS})$  Test Circuit

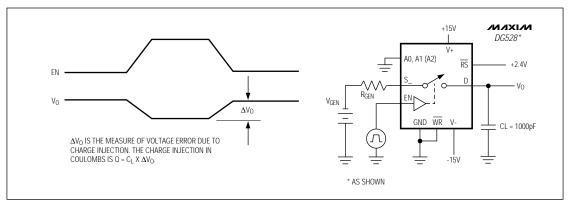


Figure 6. Charge-Injection Test Circuit

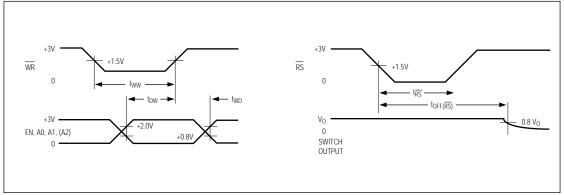


Figure 7. Typical Timing Diagrams for DG528/DG529

Table 1. DG528 Logic States

A2	A1	A0	EN	WR	RS	ON SWITCH		
Latching								
Х	Х	Х	Х	Ţ	1	Maintains previous switch condition		
Rese	t							
Х	Х	Х	Х	Х	0	None (latches cleared)		
Trans	sparen	t Oper	ation					
Х	Х	Х	0	0	1	None		
0	0	0	1	0	1	1		
0	0	1	1	0	1	2		
0	1	0	1	0	1	3		
0	1	1	1	0	1	4		
1	0	0	1	0	1	5		
1	0	1	1	0	1	6		
1	1	0	1	0	1	7		
1	1	1	1	0	1	8		

Table 2. DG529 Logic States

A1	Α0	EN	WR	RS	ON SWITCH				
Latching									
Х	Х	Х	ſ	1	Maintains previous switch condition				
Reset									
Х	Х	Х	Х	0	None (latches cleared)				
Trans	Transparent Operation								
X 0	X 0	0	0	1 1	None 1				
0	1	1	0	1	2				
1	0	1	0	1	3				
1	1	1	0	1	4				

**Note:** Logic "1": V<sub>AH</sub> ≥ 2.4V, Logic "0": V<sub>AL</sub> ≤ 0.8V.

#### Detailed Description

The internal structures of the DG528/DG529 include translators for the A2/A1/A0/EN/WR/RS digital inputs, latches, and a decode section for channel selection (Truth Tables). The gate structures consist of parallel combinations of N and P MOSFETs.

WRITE (WR) and RESET (RS) strobes are provided for interfacing with  $\mu$ P-bus lines (Figure 9), alleviating the need for the  $\mu$ P to provide constant address inputs to the mux to hold a particular channel.

When the  $\overline{\text{WR}}$  strobe is in the low state (less than 0.8V) and the  $\overline{\text{RS}}$  strobe is in the high state (greater than 2.4V), the muxes are in the transparent mode—they act similarly to nonlatching devices, such as the DG508A/DG509A or the HI508/HI509.

When the  $\overline{WR}$  goes high, the previous BCD address input is latched and held in that state indefinitely. To pull the mux out of this state, either  $\overline{WR}$  must be taken

low to the transition state, or  $\overline{\text{RS}}$  must be taken low to turn off all channels.

RS turns off all channels when it is low, which resets channel selection to the channel 1 mode.

The DG528/DG529 work with both single and dual supplies and function over the +5V to +30V single-supply range. For example, with a single +15V power supply, analog signals in the 0V to +15V range can be switched normally. If negative signals around 0V are expected, a negative supply is needed. However, only -5V is needed to normally switch signals in the -5V to +15V range (-5V, +15V supplies). No current is drawn from the negative supply, so Maxim's MAX635 DC-DC converter is an ideal choice.

The EN latch allows all switches to be turned off under program control. This is useful when two or more DG528s are cascaded to build 16-line and larger analog-signal multiplexers.

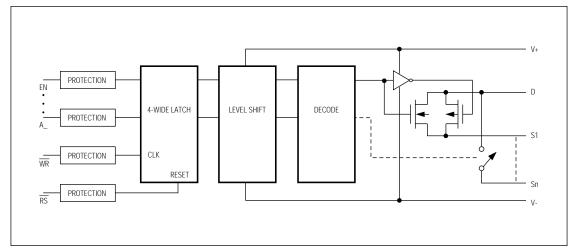


Figure 8. Simplified Internal Structure

#### \_Applications

#### Operation with Supply Voltages Other Than ±15V

Maxim guarantees the DG528/DG529 for operation from  $\pm 4.5 V$  to  $\pm 20 V$  supplies. The switching delays increase by about a factor of two at  $\pm 5 V$ , and breakbefore-make action is preserved.

The DG528/DG529 can operate with a single +5V to +30V supply as well as asymmetrical power supplies like +15V and -5V. The digital threshold will remain approximately 1.6V above the GND pin, and the analog characteristics such as rDS(ON) are determined by the total voltage difference between V+ and V-. Connect V-to 0V when operating with a +5V to +30V single supply.

#### Digital Interface Levels

The typical digital threshold of both the address lines and EN is 1.6V with a temperature coefficient of approximately -3mV/°C, ensuring compatibility with TTL logic over the temperature range. The digital threshold is relatively independent of the power-supply voltages, going from a typical 1.6V when V+ is 15V to 1.5V typical with V+ = 5V. Therefore, Maxim's DG528/DG529 operate with standard TTL logic levels, even with ±5V power supplies. In all cases, EN's threshold is the same as the other logic inputs and is referenced to GND.

The digital inputs can also be driven with CMOS logic levels swinging from either V+ to V- or from V+ to GND. The digital input current is just a few nanoamps of leakage at all input-voltage levels with a guaranteed maximum of  $1\mu A$ . The digital inputs are protected from ESD by a 30V zener diode between the input and V+ and can be driven  $\pm 2V$  beyond the supplies without drawing excessive current.

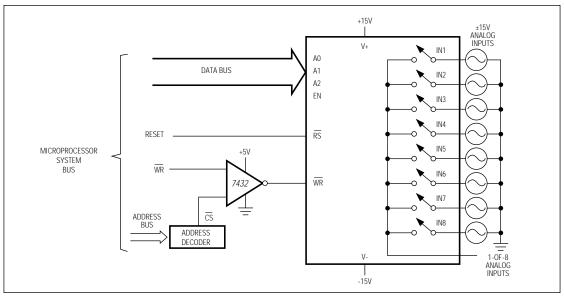
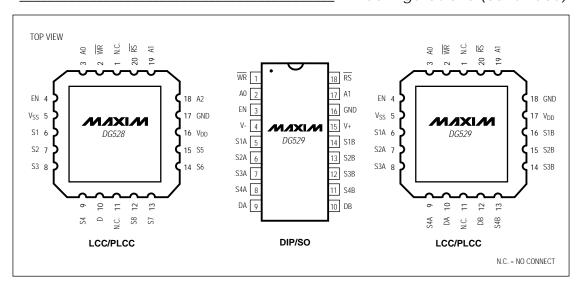


Figure 9. Bus Interface

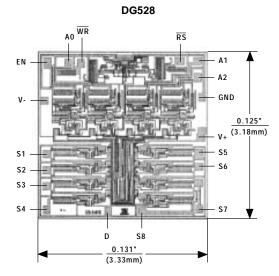
#### Pin Configurations (continued)



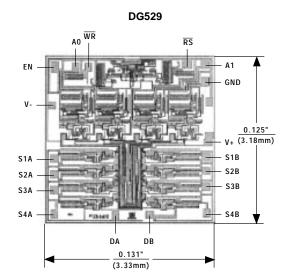
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DG529AZ	-55°C to +125°C	20 LCC**
DG529AK	-55°C to +125°C	18 CERDIP**

### Chip Topographies

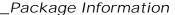


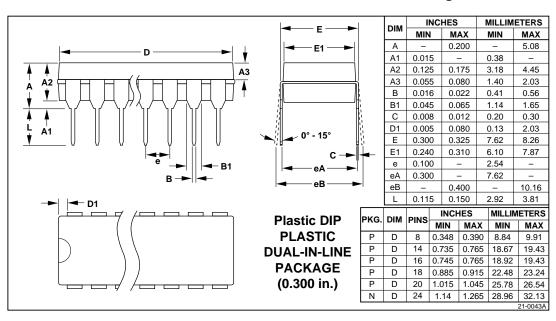
TRANSISTOR COUNT: 200 SUBSTRATE CONNECTED TO V+

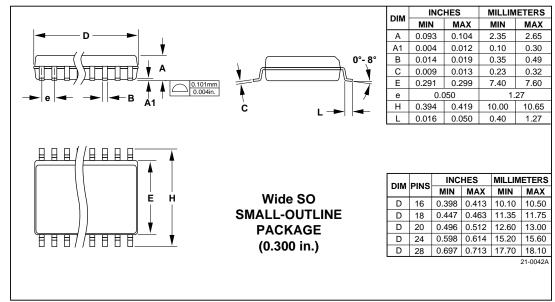


TRANSISTOR COUNT: 200 SUBSTRATE CONNECTED TO V+

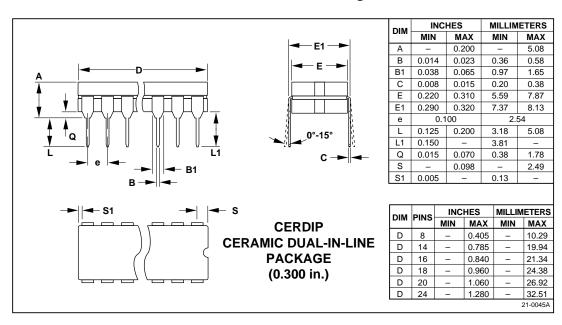
<sup>\*</sup> Contact factory for dice specifications. \*\* Contact factory for availability and processing to MIL-STD-883.











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DG528AK/883B DG529AK/883B DG528CWN+ DG529CWN+ DG528CCWN+ DG528CJ+ DG528CWN+T DG528EWN+T DG529CJ+ DG529CWN+T DG529DJ+